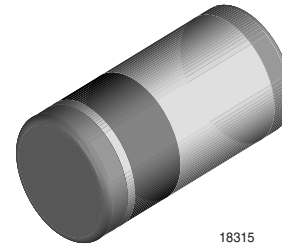


Zener Diodes

Features

- Silicon Planar Power Zener Diodes.
- For use in stabilizing and clipping circuits with high power rating.
- Standard Zener voltage tolerance is $\pm 5\%$.
- These diodes are also available in the DO-41 case with type designation 1N4728 A... 1N4764A



Mechanical Data

Case: MELF Glass Case

Weight: approx. 250 mg

Packaging Codes/Options:

E4 / 5k per 13 " reel (12 mm tape), 10k/box

25 / 1.5 K per 7 " reel (12 mm tape), 12k/box

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Zener current (see Table "Characteristics")				
Power dissipation		P_{tot}	1.0 ¹⁾	W

¹⁾ Valid provided that electrodes are kept at ambient temperature.

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		$R_{\theta JA}$	170 ¹⁾	$^{\circ}\text{C}/\text{W}$
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature		T_S	- 65 to + 150	$^{\circ}\text{C}$

¹⁾ Valid provided that electrodes are kept at ambient temperature.

ZM4728 to ZM4764A



Vishay Semiconductors

Electrical Characteristics

Partnumber	Nominal Zener Voltage ³⁾	Test Current	Maximum Zener Impedance ¹⁾			Maximum Reverse Leakage Current		Surge current	Maximum Reverse Leakage Current ²⁾
			Z _{ZT} @ I _{ZT}	Z _{ZK} @ I _{ZK}	I _{ZK}	I _R	V _R		
	V _Z @ I _{ZT}	I _{ZT}	Z _{ZT} @ I _{ZT}	Z _{ZK} @ I _{ZK}	I _{ZK}	I _R	V _R	I _R @ T _{amb} = 25 °C	I _{ZM}
	V	mA	Ω		mA	μA	V	mA	μA
ZM4728	3.3	76	10	400	1	100	1	1380	276
ZM4729	3.6	69	10	400	1	100	1	1260	252
ZM4730	3.9	64	9	400	1	50	1	1190	234
ZM4731	4.3	58	9	400	1	10	1	1070	217
ZM4732	4.7	53	8	500	1	10	1	970	193
ZM4733	5.1	49	7	550	1	10	1	890	178
ZM4734	5.6	45	5	600	1	10	2	810	162
ZM4735	6.2	41	2	700	1	10	3	730	146
ZM4736	6.8	37	3.5	700	1	10	4	660	133
ZM4737	7.5	34	4	700	0.5	10	5	605	121
ZM4738	8.2	31	4.5	700	0.5	10	6	550	110
ZM4739	9.1	28	5	700	0.5	10	7	500	100
ZM4740	10	25	7	700	0.25	10	7.6	454	91
ZM4741	11	23	8	700	0.25	5	8.4	414	83
ZM4742	12	21	9	700	0.25	5	9.1	380	76
ZM4743	13	19	10	700	0.25	5	9.9	344	69
ZM4744	15	17	14	700	0.25	5	11.4	304	61
ZM4745	16	15.5	16	700	0.25	5	12.2	285	57
ZM4746	18	14	20	750	0.25	5	13.7	250	50
ZM4747	20	12.5	22	750	0.25	5	15.2	225	45
ZM4748	22	11.5	23	750	0.25	5	16.7	205	41
ZM4749	24	10.5	25	750	0.25	5	18.2	190	38
ZM4750	27	9.5	35	750	0.25	5	20.6	170	34
ZM4751	30	8.5	40	1000	0.25	5	22.8	150	30
ZM4752	33	7.5	45	1000	0.25	5	25.1	135	27
ZM4753	36	7	50	1000	0.25	5	27.4	125	25
ZM4754	39	6.5	60	1000	0.25	5	29.7	115	23
ZM4755	43	6	70	1500	0.25	5	32.7	110	22
ZM4756	47	5.5	80	1500	0.25	5	35.8	95	19
ZM4757	51	5	95	1500	0.25	5	38.8	90	18
ZM4758	56	4.5	110	2000	0.25	5	42.6	80	16
ZM4759	62	4	125	2000	0.25	5	47.1	70	14
ZM4760	68	3.7	150	2000	0.25	5	51.7	65	13
ZM4761	75	3.3	175	2000	0.25	5	56	60	12
ZM4762	82	3	200	3000	0.25	5	62.2	55	11
ZM4763	91	2.8	250	3000	0.25	5	69.2	50	10
ZM4764	100	2.5	350	3000	0.25	5	76	45	9

¹⁾ The Zener impedance is derived from the 1KHz AC voltage which results when an AC current having an RMS value equal to 10 % of the Zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK}. Zener impedance is measured at two points to insure a sharp knee on the breakdown curve and to eliminate unstable units

²⁾ Valid provided that electrodes at a distance of 10 mm from case are kept at ambient temperature

³⁾ Measured under thermal equilibrium and DC test conditions.

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

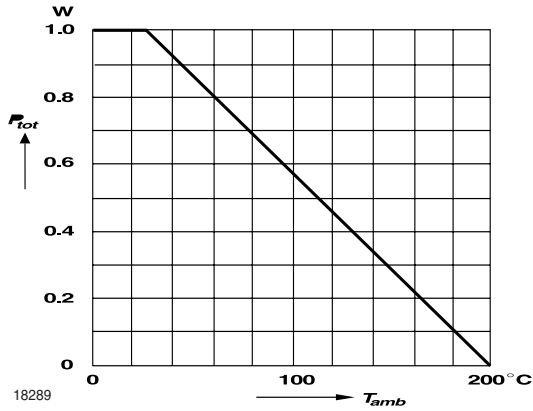
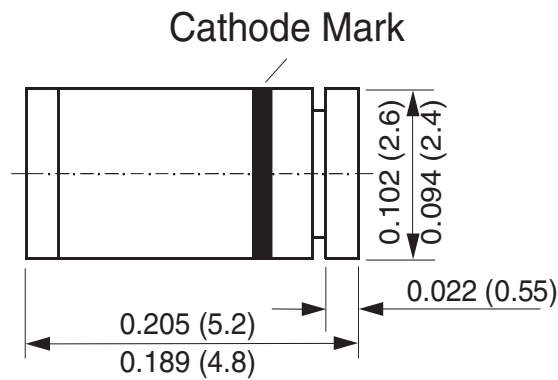


Figure 1. Admissible Power Dissipation vs. Ambient Temperature

Package Dimensions in Inches (mm)



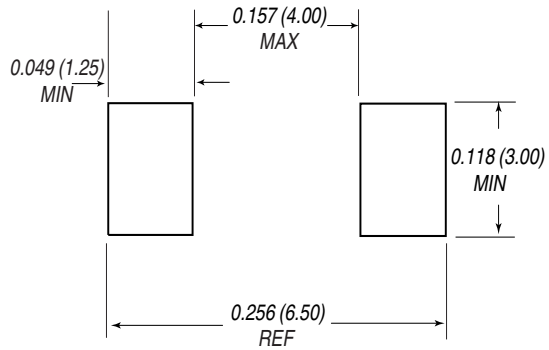
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ZM4728 to ZM4764A

Vishay Semiconductors



Mounting Pad Layout



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Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design
and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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